

$V_{DSS}$	600V
$R_{DS(on)}$ (Max.)	0.130Ω
$I_D$	±30A
$P_D$	305W

### ●Outline

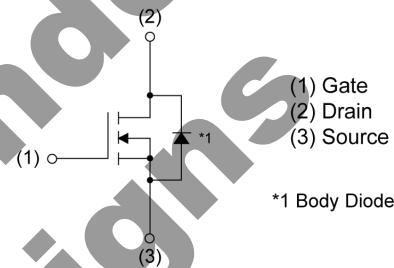
TO-247



### ●Features

- 1) Low on-resistance.
- 2) Ultra fast switching speed.
- 3) Parallel use is easy.
- 4) Pb-free lead plating ; RoHS compliant

### ●Inner circuit



### ●Packaging specifications

Type	Packing	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	450
	Taping code	C9
	Marking	R6030KNZ1

### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ , unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	$V_{DSS}$	600	V
Continuous drain current ( $T_c = 25^\circ\text{C}$ )	$I_D^{*1}$	±30	A
Pulsed drain current	$I_{DP}^{*2}$	±90	A
Gate - Source voltage	$V_{GSS}$ static	±20	V
	$V_{GSS}$ AC( $f > 1\text{Hz}$ )	±30	V
Avalanche current, single pulse	$I_{AS}$	5.2	A
Avalanche energy, single pulse	$E_{AS}^{*3}$	636	mJ
Power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_D$	305	W
Junction temperature	$T_j$	150	°C
Operating junction and storage temperature range	$T_{stg}$	-55 to +150	°C

### ● Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	$R_{thJC}$ <sup>*4</sup>	-	-	0.41	°C/W
Thermal resistance, junction - ambient	$R_{thJA}$	-	-	30	°C/W
Soldering temperature, wavesoldering for 10s	$T_{sold}$	-	-	265	°C

### ● Electrical characteristics ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$	600	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$	-	-	100	$\mu\text{A}$
		$T_j = 25^\circ\text{C}$	-	-	1000	
Gate - Source leakage current	$I_{GSS}$	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$	-	-	$\pm 100$	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10\text{V}, I_D = 1\text{mA}$	3	-	5	V
Static drain - source on - state resistance	$R_{DS(on)}$ <sup>*5</sup>	$V_{GS} = 10\text{V}, I_D = 14.5\text{A}$	-	0.115	0.130	$\Omega$
		$T_j = 25^\circ\text{C}$	-	0.24	-	
Gate resistance	$R_G$	$f = 1\text{MHz}, \text{open drain}$	-	2.1	-	$\Omega$

● Electrical characteristics ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Forward Transfer Admittance	$ Y_{fs} ^{*5}$	$V_{DS} = 10\text{V}, I_D = 15\text{A}$	10	20	-	S
Input capacitance	$C_{iss}$	$V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$	-	2350	-	pF
Output capacitance	$C_{oss}$		-	2000	-	
Reverse transfer capacitance	$C_{rss}$		-	140	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \approx 300\text{V}, V_{GS} = 10\text{V}$ $I_D = 15\text{A}$ $R_L \approx 20\Omega$ $R_G = 10\Omega$	-	36	-	ns
Rise time	$t_r^{*5}$		-	75	-	
Turn - off delay time	$t_{d(off)}^{*5}$		-	90	-	
Fall time	$t_f^{*5}$		-	45	-	

● Gate charge characteristics ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	$Q_g^{*5}$	$V_{DD} \approx 300\text{V}$ $I_D = 30\text{A}$ $V_{GS} = 10\text{V}$	-	56	-	nC
Gate - Source charge	$Q_{gs}^{*5}$		-	18	-	
Gate - Drain charge	$Q_{gd}^{*5}$		-	23	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} \approx 300\text{V}, I_D = 30\text{A}$	-	6.3	-	V

\*1 Limited only by maximum channel temperature allowed.

\*2  $P_w \leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$

\*3  $L = 50\text{mH}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , STARTING  $T_j = 25^\circ\text{C}$

\*4  $T_C = 25^\circ\text{C}$

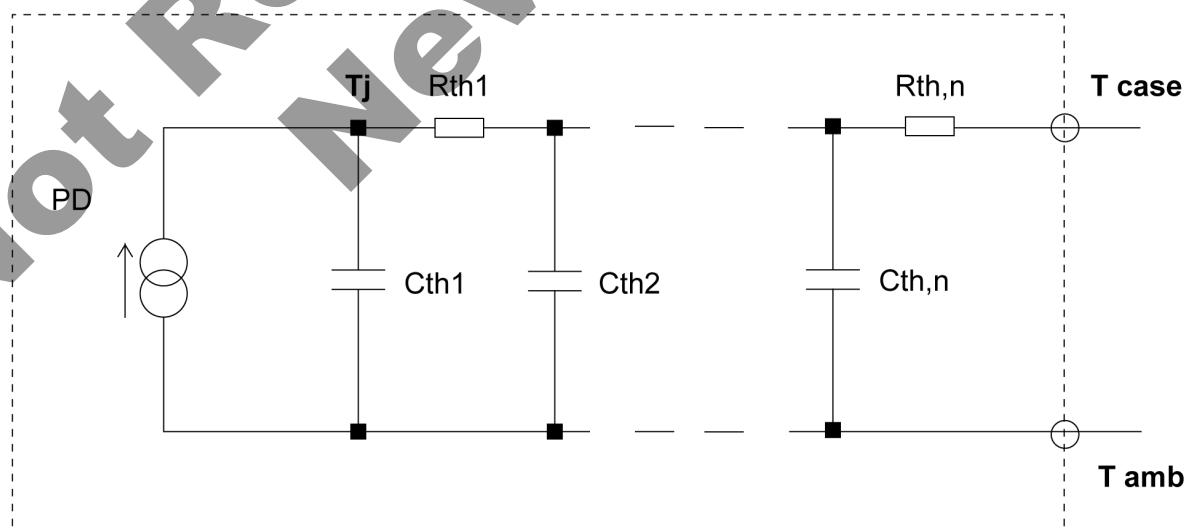
\*5 Pulsed

● Body diode electrical characteristics (Source-Drain) ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous forward current	$I_S^{*1}$	$T_C = 25^\circ\text{C}$	-	-	30	A
Pulse forward current	$I_{SP}^{*2}$		-	-	90	A
Forward voltage	$V_{SD}^{*5}$	$V_{GS} = 0\text{V}, I_S = 30\text{A}$	-	-	1.5	V
Reverse recovery time	$t_{rr}$	$I_S = 30\text{A}$ $dI/dt = 100\text{A}/\mu\text{s}$	-	517	-	ns
Reverse recovery charge	$Q_{rr}$		-	9.6	-	$\mu\text{C}$
Peak reverse recovery current	$I_{rmn}$		-	37	-	A

● Typical transient thermal characteristics

Symbol	Value	Unit	Symbol	Value	Unit
$R_{th1}$	0.190	K/W	$C_{th1}$	0.0143	Ws/K
$R_{th2}$	0.429		$C_{th2}$	0.322	
$R_{th3}$	0.250		$C_{th3}$	14.7	



● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

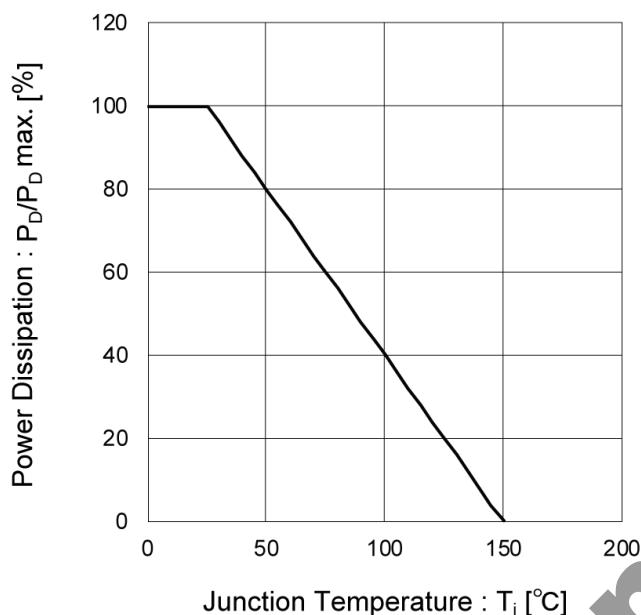


Fig.2 Maximum Safe Operating Area

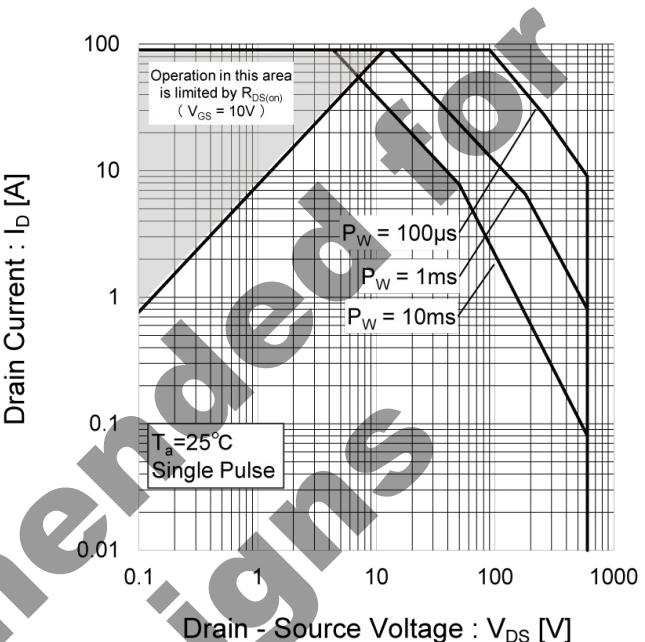
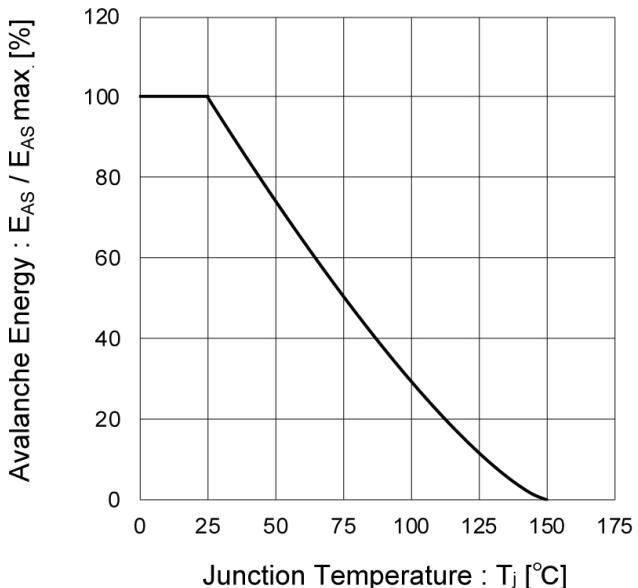


Fig.3 Avalanche Energy Derating Curve vs. Junction Temperature



**●Electrical characteristic curves**

Fig.4 Typical Output Characteristics(I)

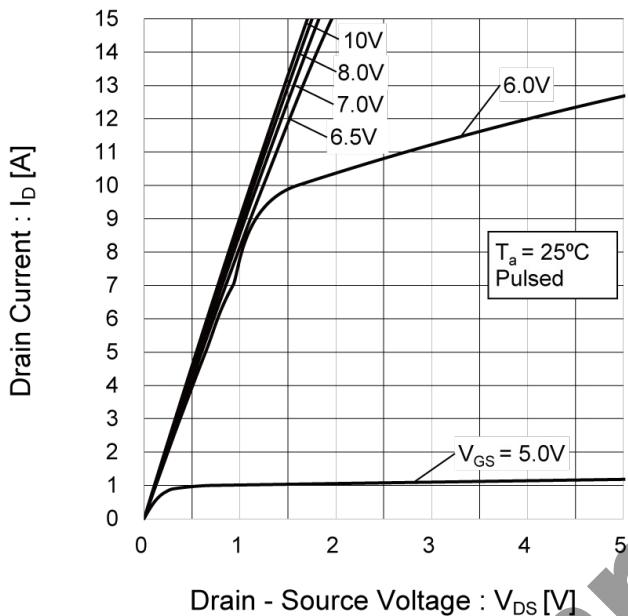
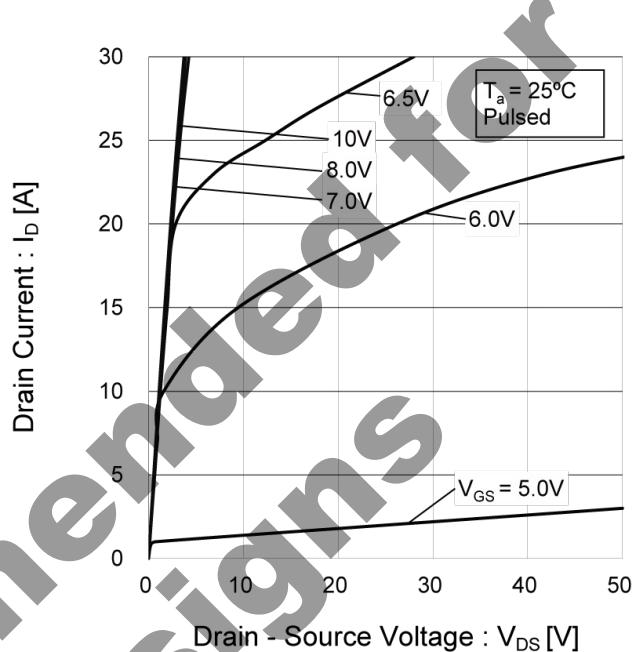


Fig.5 Typical Output Characteristics(II)



Not Recommended  
New Designs

## ● Electrical characteristic curves

Fig.6 Breakdown Voltage vs.  
Junction Temperature

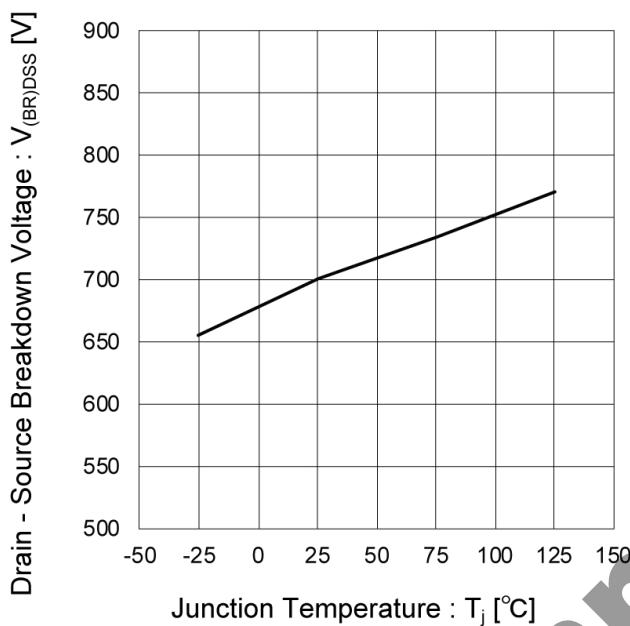


Fig.7 Typical Transfer Characteristics

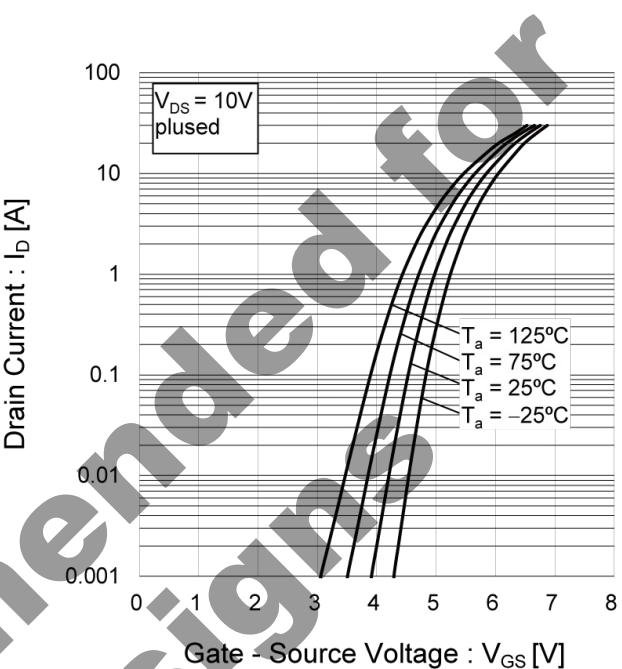


Fig.8 Gate Threshold Voltage vs.  
Junction Temperature

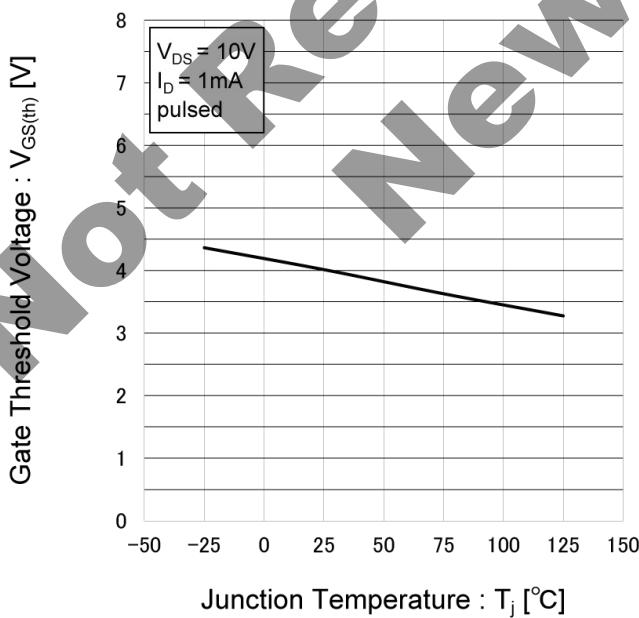
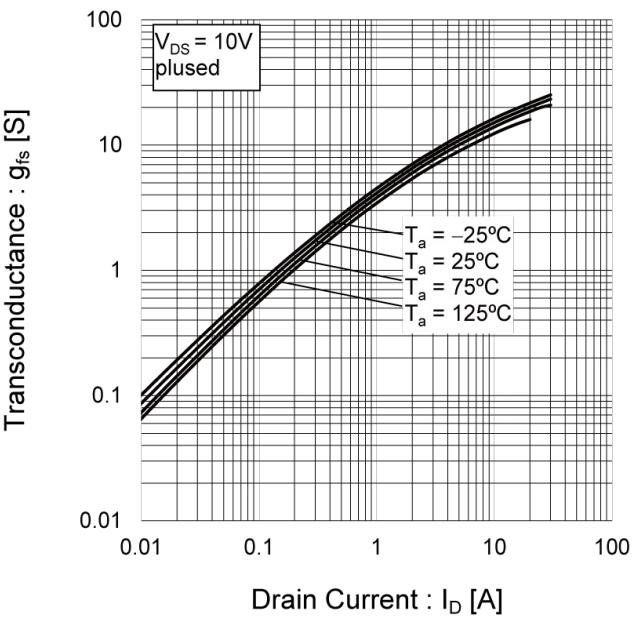


Fig.9 Forward Transfer Admittance vs.  
Drain Current



● Electrical characteristic curves

Fig.10 Static Drain - Source On - State  
Resistance vs. Gate Source Voltage

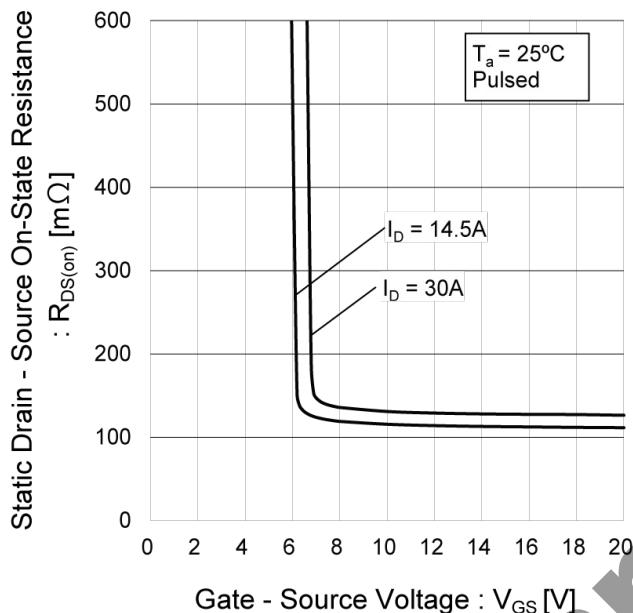


Fig.11 Static Drain - Source On - State  
Resistance vs. Junction Temperature

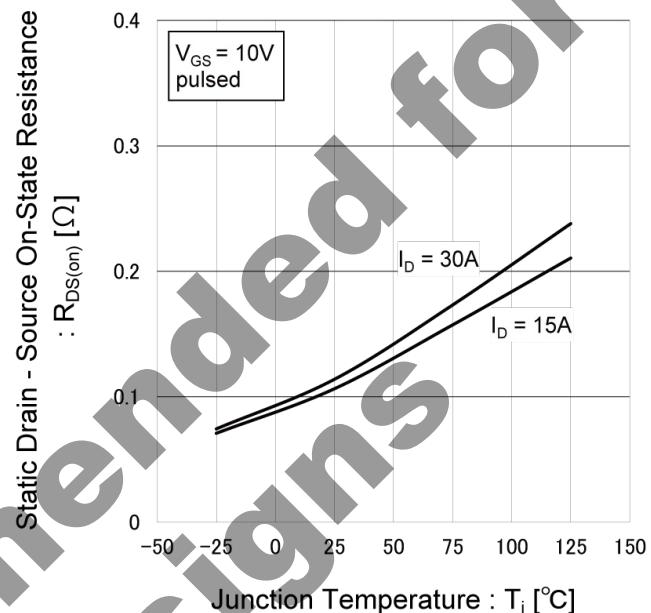
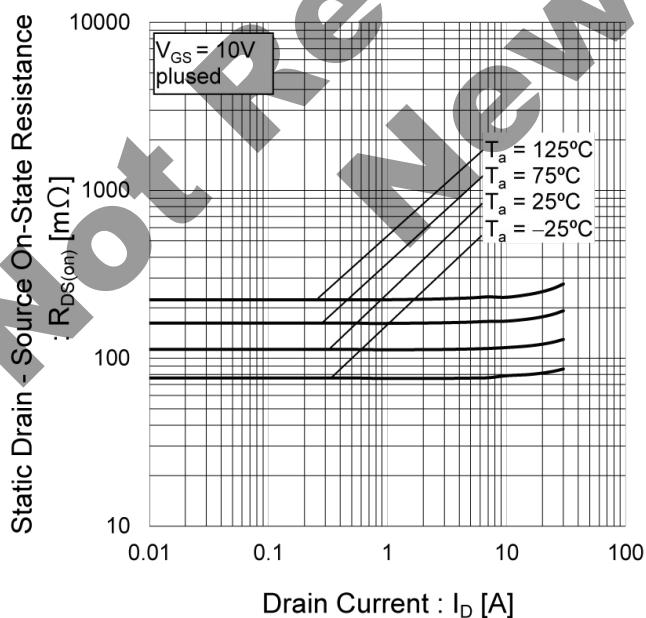


Fig.12 Static Drain - Source On - State  
Resistance vs. Drain Current( $I_D$ )



● Electrical characteristic curves

Fig.13 Typical Capacitance vs.  
Drain - Source Voltage

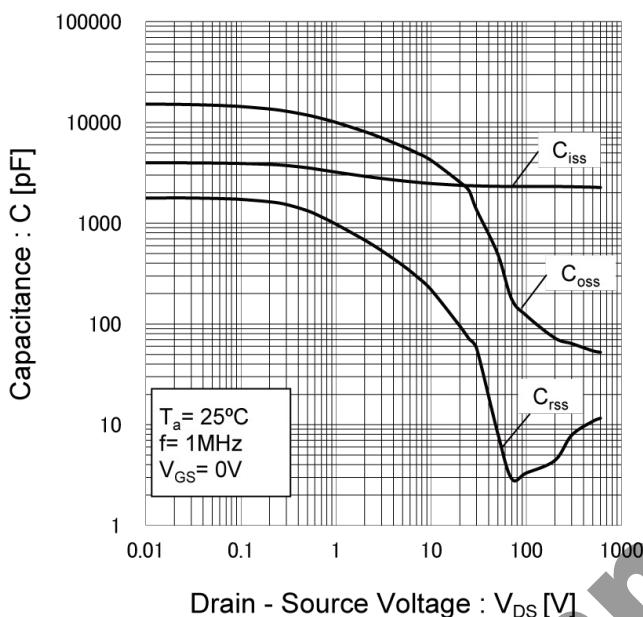


Fig.14 Switching Characteristics

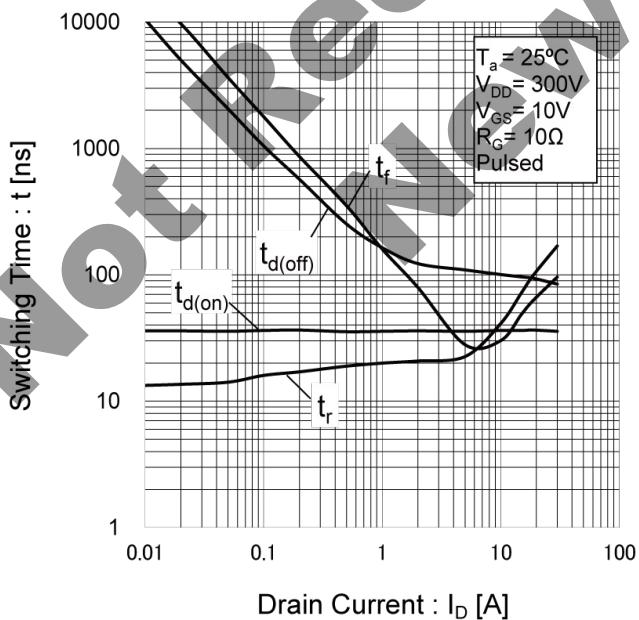
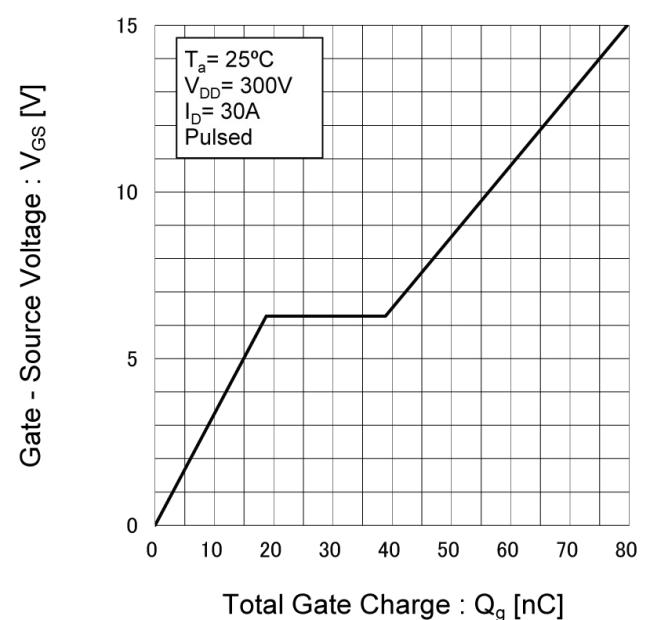


Fig.15 Dynamic Input Characteristics



**●Electrical characteristic curves**

Fig.16 Inverse Diode Forward Current  
vs. Source - Drain Voltage

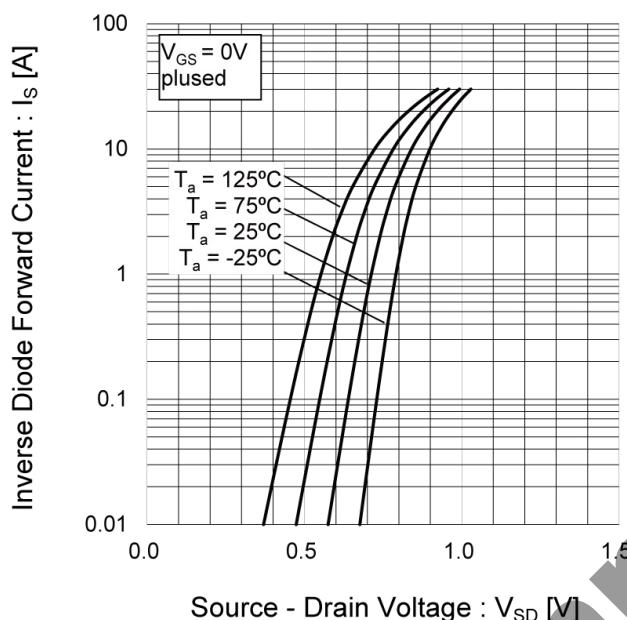
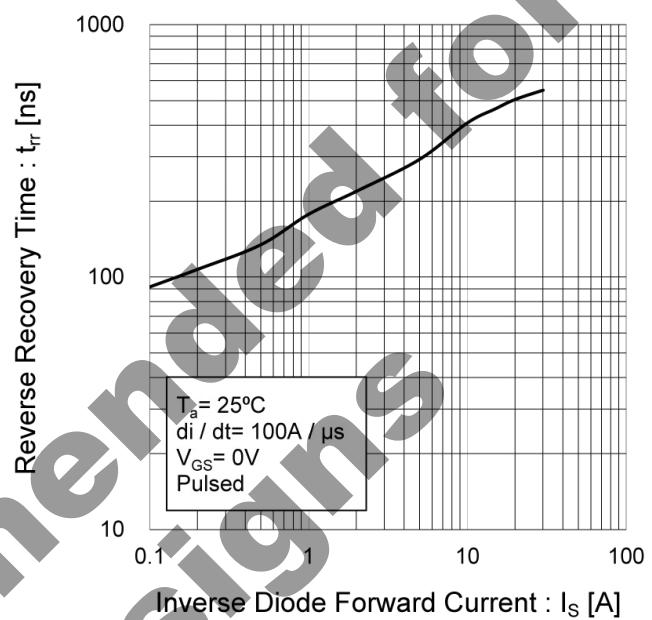


Fig.17 Reverse Recovery Time vs.  
Inverse Diode Forward Current



## ● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

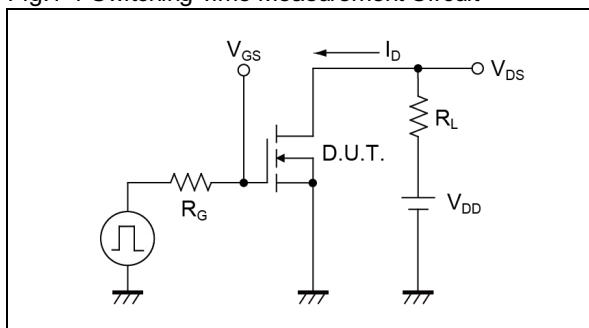


Fig.1-2 Switching Waveforms

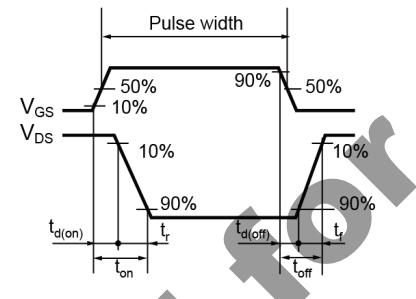


Fig.2-1 Gate Charge Measurement Circuit

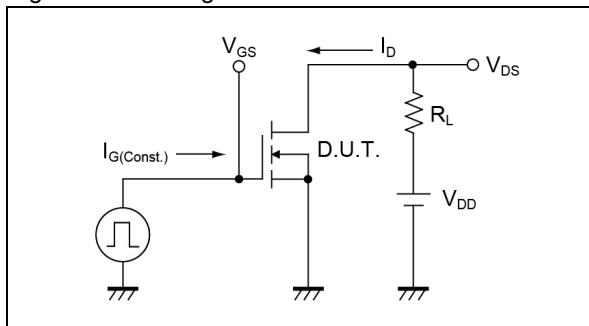


Fig.2-2 Gate Charge Waveform

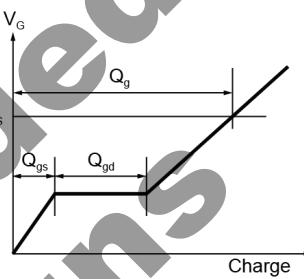


Fig.3-1 Avalanche Measurement Circuit

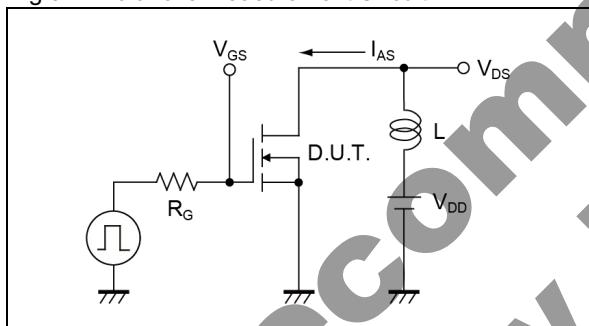


Fig.3-2 Avalanche Waveform

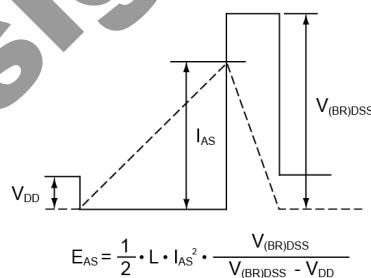


Fig.4-1 dv/dt Measurement Circuit

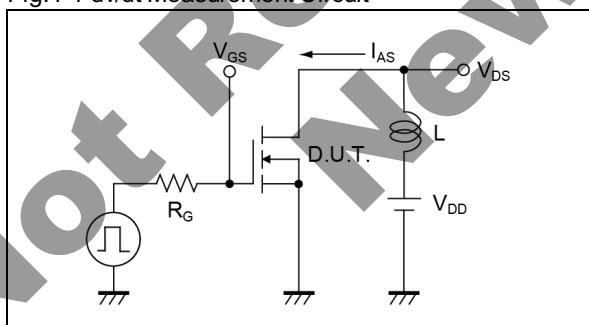


Fig.4-2 dv/dt Waveform

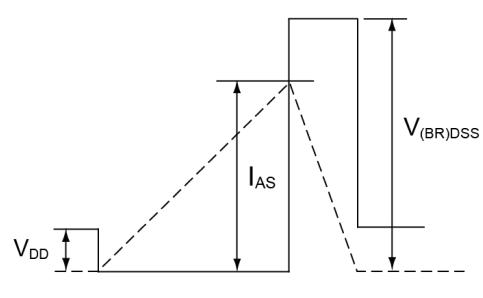


Fig.5-1 dv/dt Measurement Circuit

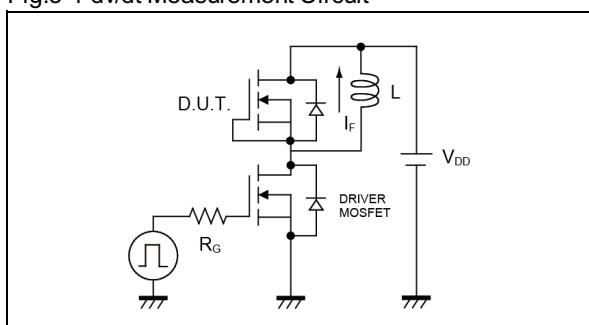
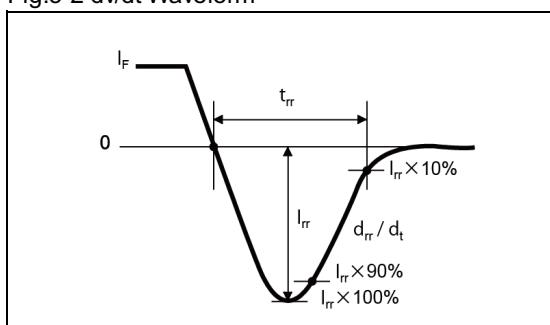
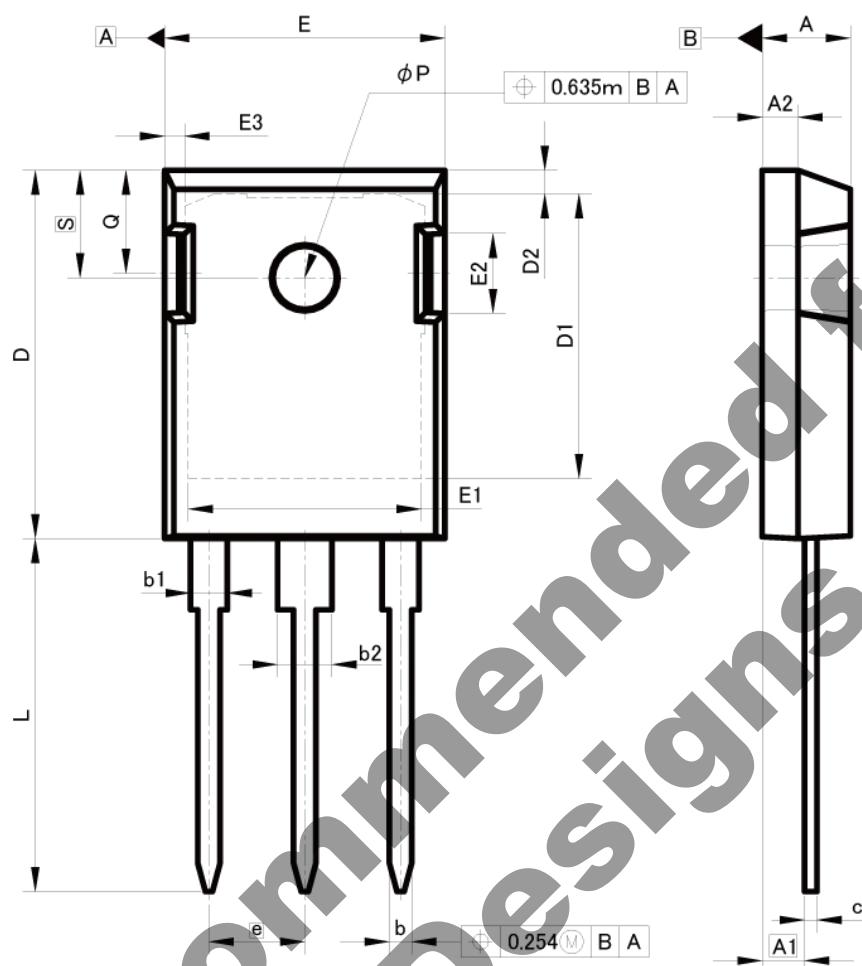


Fig.5-2 dv/dt Waveform



## ●Dimensions

TO-247



DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.83	5.21	0.19	0.205
A1	2.29	2.54	0.09	0.1
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b1	1.91	2.20	0.075	0.087
b2	2.92	3.20	0.115	0.126
c	0.61	0.80	0.024	0.031
D	20.80	21.34	0.819	0.84
D1	17.43	17.83	0.686	0.702
E	15.75	16.13	0.62	0.635
e	5.45		0.22	
N	3		3	
L	19.81	20.57	0.78	0.81
L1	3.81	4.07	0.15	0.16
φP	3.55	3.65	0.14	0.144
Q	5.59	6.20	0.22	0.244
S	6.15		0.24	

Dimension in mm/inches

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